

High precision inductive proximity switch IC

Order information

Package

SOP8

Introduction

The LDA355 (instead of TCA355) is an ASIC developed for inductive proximity switch applications. It can be used in a wide range of proximity sensors or proximity control systems. It can also be used to make a variety of inductive instrumentation such as inductive tachometers.

LDA355 has the characteristics of high integration, wide working voltage, large output current, adjustable control distance, few peripheral circuits, convenient application and stable and reliable operation. Compared with the inductive proximity switch scheme composed of general discrete components, the LDA355 integrated chip solution has better consistency and stability, so it is especially suitable for high reliability and high reliability.

Feature

- Low current consumption: < 0.7mA
- Wide supply voltage: 4.0^{40V}
- Low saturation pressure drop •
- Built-in temperature compensation
- High sensitivity and low inductance requirements
- Hysteresis is not related to temperature, voltage and distance
- Output tube switching frequency is high
- Output tube drive current >70mA
- Range of working temperature −40[~]+125°C

Typical application

- Inductive proximity switch
- Contactless switch
- Position control
- Isolation detection
- Speed measurement

Pin	Symbol	Function	
1	GND	Ground	
2	RDI	Distance setting resistor	
3	CI	Integral capacitor	
4	Q2	Output 2	
5	Q1	Output 1	
6	VCC	Voltage	
7	LC	Oscillator	
8	RHY	Backlash setting resistor	

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Pin Configurations

Remarks

Tubed, Reeled, Pb-free

8
7
6
5

LDA355

1	0	8
2		7
3		6
4		5



LDA355

Recommended working conditions

Parameter	Symbol	Value	Unit
Voltage	Vcc	4.0 ~ 40	V
Range of working temperature	Тор	-40 $^{\sim}$ $+125$	°C

Limit parameter

Parameter	Symbol	Value	Unit	
Voltage	Vcc	-0.3 ~ +50	V	
Output voltage	Vout(off)	-1 ~ +45	V	
Output low level current	IOUT(SINK)	70	mA	
VREF pin current	-IVREF	100	μΑ	
RDI pin current	-IRDI	2	mA	
RHYS pin current	IRHYS	2	mA	
Maximum junction temperature	Tj(max)	+150	°C	
Storage temperature	Tst	-55 ~ +160	°C	

Electrical parameters Typical test conditions $V_{CC}=12V$ and $T_A=25^{\circ}C$, unless otherwise indicated.

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Minimum starting voltage	Output start action	V _{TON}	-	3.64	4	V
Shutdown voltage	Output from action to no action	V _{TOFF}	3.0	3.6	-	V
Hysteresis		ΔV_{HY}	-	0.04	-	V
Quiescent Current		I _{CC}	-	0.55	0.70	mA
Oscillating frequency		f _{osc}	-	-	3	MHz
Oscillation amplitude		Aosc	-	0.8	-	Vpp
CI pin threshold		V _{CI}	-	2	-	V
CI pin hysteresis		V _{HYCI}	-	7	-	V
CI pin sink current		I _{CI}	-	7	-	μΑ
CI pin pull current		-I _{CI}	-	6	-	μΑ
On-off level frequency	CI<50pF, L=70µH	fs	-	5	-	kHz
Reference voltage	I _{VREF} =0~100μA	V _{REF}	2.65	3.00	3.10	V
Switch tube conduction	I _Q =5mA	V	-	0.10	0.14	V
voltage drop	I _Q =70mA	V _{QR}	V QR -	0.50	0.99	

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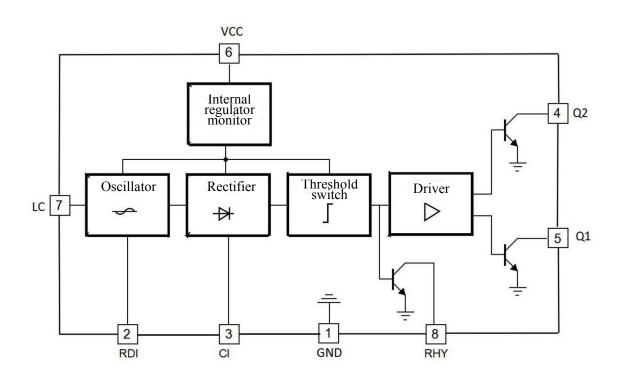


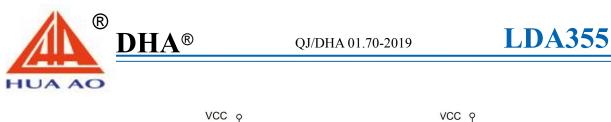
Figure 1. Internal block diagram

Working principle

The LC oscillator produces an alternating magnetic field. When the metal target approaches this magnetic field and reaches the sensing distance, eddy currents are generated in the metal target, causing the oscillation to decay and even stop. The oscillation and oscillation of the oscillator are processed by the post-amplifier circuit and converted into a switching signal to trigger the drive control device to achieve the non-contact detection purpose. The LDA355 works only by externally connected inductor L and resonant capacitor C to generate oscillations and generate alternating magnetic fields. The other peripheral components are shown in Figure 2. Two resistors, RDI and RHY, are used to set the sensing distance and hysteresis. In addition, the integrating capacitor CI is connected to pin 3 for internal signal sampling.

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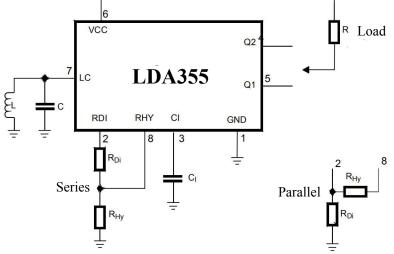


Figure 2. Working principle diagram

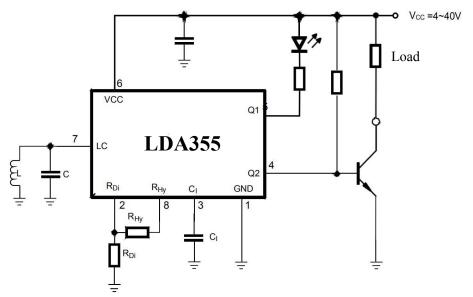


Figure 3. Three-wire NPN normally open application circuit diagram

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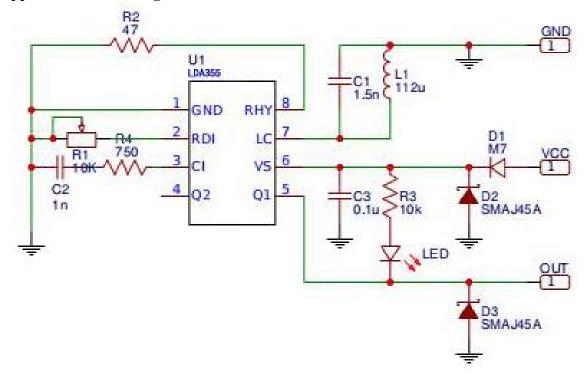
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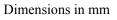
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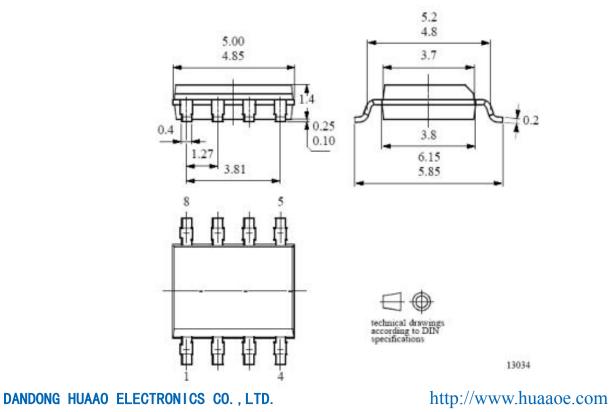
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Application circuit diagram



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